Diode Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Ceramic

**Overall Length:** 

0.300 inches

# Terminal Length:

0.975 inches

## **Overall Diameter:**

0.145 inches

#### **Mounting Method:**

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

340.0 regulator voltage

### Voltage Tolerance In Percent:

-5.0/+5.0

## **Current Rating Per Characteristic:**

4.00 milliamperes all primaries horsepower metric and 13.00 milliamperes repetitive peak forward current

## **Power Rating Per Characteristic:**

8.0 watts small-signal input power, common-collector absolute

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Precious Material And Location:**

Terminals or terminal surfaces, options silver

## **Precious Material:**

Silver

### Test Data Document:

26916-019-005381 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

### **Terminal Type And Quantity:**

2 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

No

### Fiig:

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